TOSHIBA

TOSHIBA BI-DIRECTIONAL TRIODE THYRISTOR SILICON PLANAR TYPE

SM12G45,SM12J45,SM12G45A,SM12J45A

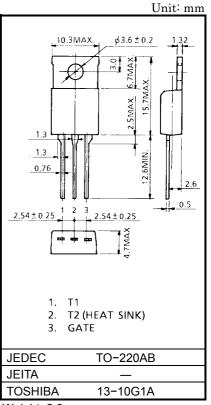
: IT (RMS) = 12A

AC POWER CONTROL APPLICATIONS

- Repetitive Peak Off-State Voltage : V_{DRM} = 400, 600V
- R.M.S On–State Current
- High Commutating (dv / dt)

MAXIMUM RATINGS

CHARACTERI	STIC	SYMBOL	RATING	UNIT	
Repetitive Peak Off–State Voltage	SM12G45 SM12G45A		400	V	
	SM12J45 SM12J45A	V _{DRM}	600	v	
R.M.S On–State Curren (Full Sine Waveform Tc		I _{T (RMS)}	12	А	
Peak One Cycle Surge On-State Current (Non-Repetitive)		le a c	120 (50Hz)	A	
		ITSM	132 (60Hz)		
I^{2} t Limit Value (t = 1~10)	ns)	l ² t	72	A ² s	
Critical Rate of Rise of C Current	0n-State	di / dt	50	Α / μs	
Peak Gate Power Dissip	ation	P _{GM}	5	W	
Average Gate Power Dis	sipation	P _{G (AV)}	0.5	W	
Peak Gate Voltage		V _{GM}	10	V	
Peak Gate Current		I _{GM}	2	А	
Junction Temperature		Tj	-40~125	°C	
Storage Temperature Ra	ange	T _{stg}	-40~125	°C	

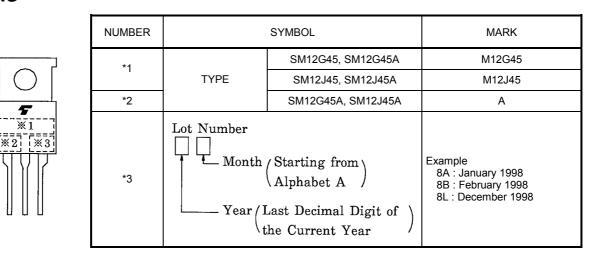


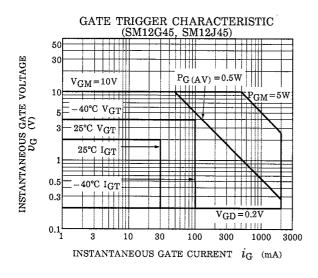
Weight: 2.0g

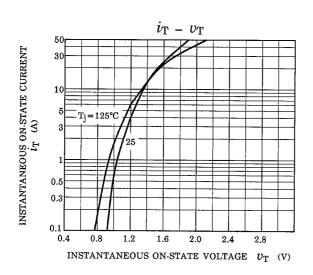
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

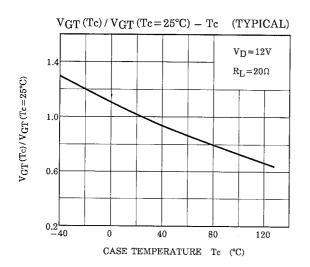
CHARACTERISTIC			SYMBOL	TEST CONDITION		MIN	TYP.	MAX	UNIT	
Repetitive Peak Off-State Current		I _{DRM}	V _{DRM} =Rated, T _j = 125°C		_	—	2	mA		
Gate Trigger Voltage			Ι	V _{GT}	V _D = 12V, R _L = 20Ω	T2 (+) , Gate (+)		_	2	- V
	SM12	2G45	П			T2 (+) , Gate (−)	_	_	2	
	SM12	2J45	III			T2 (-) , Gate (-)		_	2	
			IV			T2 (-) , Gate (+)		_		
			I			T2 (+) , Gate (+)		_	1.5	
	SM12	2G45A	П			T2 (+) , Gate (−)		_	1.5	
	SM12	2J45A	Ш			T2 (-) , Gate (-)		_	1.5	
			IV			T2 (-) , Gate (+)		_		
Gate Trigger Current			Ι	- I _{GT}	V _D = 12V, R _L = 20Ω	T2 (+) , Gate (+)		_	30	- mA
	SM12	2G45	П			T2 (+) , Gate (-)		_	30	
	SM12	2J45	Ш			T2 (-) , Gate (-)		_	30	
			IV			T2 (-) , Gate (+)		_	—	
			I			T2 (+) , Gate (+)		_	20	
	SM12	2G45A	П			T2 (+) , Gate (-)		_	20	
	SM12	SM12J45A				T2 (-) , Gate (-)		_	20	-
						T2 (-) , Gate (+)		_		
Peak On-State Voltage			V _{TM}	I _{TM} = 17A		-	_	1.5	V	
Gate Non-Trigger Voltage			V _{GD}	V _D = Rated, Tc = 125°C		0.2	_	_	V	
Holding Current			Ι _Η	V _D = 12V, I _{TM} = 1A			_	50	mA	
Thermal Resistance			R _{th (j−c)}	Junction to Case, AC		-	_	1.8	°C/W	
Critical Rate of Rise of Off-State Voltage at Commutation SM12G45 SM12J45 SM12G45A SM12G45A SM12J45A		(dv / dt) c	V _{DRM} = 400V		10	_	_	V/µs		
					(di / dt) c = - 6.5A / ms		4	_	_	v / µs

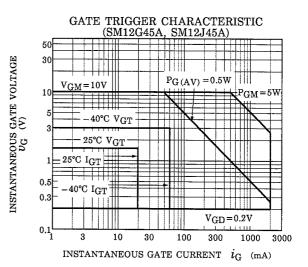
MARKING

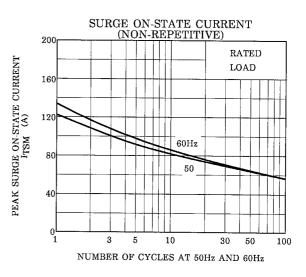


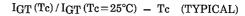


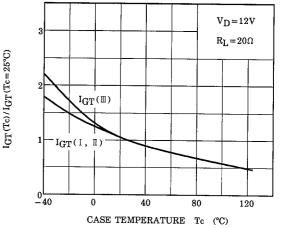




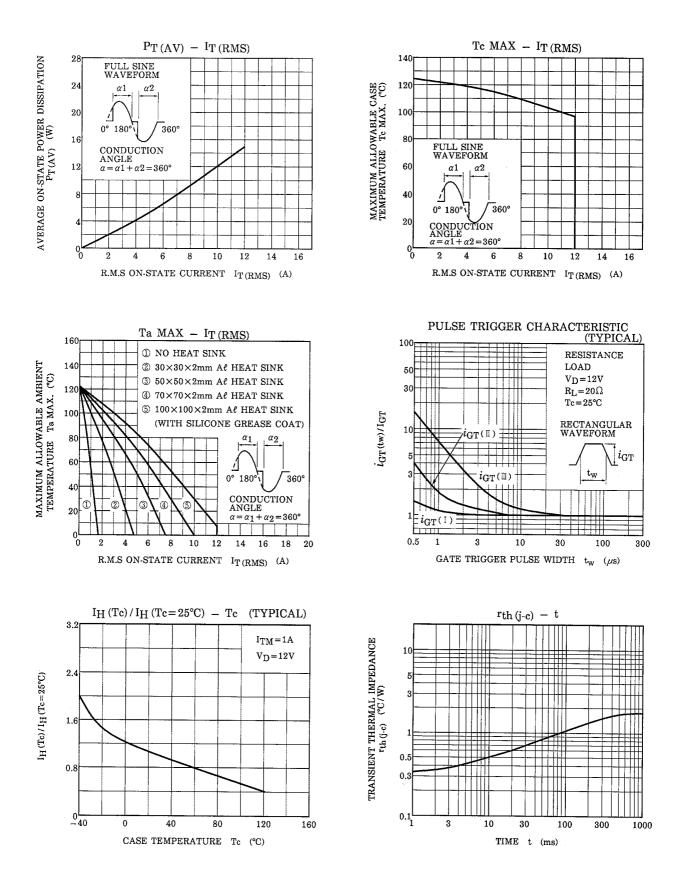








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